CG...BINED DECLARATION AND POWER OF ATTORNLY FOR PATENT APPLICATION (Page 1)

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As a below	v named inventor, I hereby declare	that:		
My resider	nce, post office address and citizen	ship are as stated below next	to my name;	COPY
	am the original, first and sole inver			
names are listed be	elow) of the subject matter which i DUCTOR ELEMENT A	s claimed and for which a pa	tent is sought on the in	vention entitled
SEMICON	DOCTOR ELEMENT A	ND 115 MANUTAC	JUNING MET	HOD .
		¬ ,	10 1000	
	which is attached hereto			
	ational Application No.	09/266.829)	
and was amended o	on	· · · · · · · · · · · · · · · · · · ·		(if applicable)
	tate that I have reviewed and und nendment referred to above.	lerstand the contents of the a	bove-identified specific	cation, including the claims, a
I acknowle	edge the duty to disclose information	on which is material to patent	ability as defined in 37	CFR §1.56.
inventor's certificate listed below and he	laim foreign priority benefits und te, or § 365(a) of any PCT interna ave also identified below any fore before that of the application on	tional application which desiging application for patent or	nates at least one count	ry other than the United States
Country	Application No.	Filed (Day/Mo./	Yr.)	(Yes/No) Priority Claimed
JAPAN	10-065287	16 March	1998	YES
JAPAN	10-066854	17 March	1998	YES
to transact all busin	point the practitioners associated was in the Patent and Trademark with that Customer Number: FITZPAT	oith the firm and Customer No Office connected therewith, a RICK, CELLA, HARPER & Customer Number: 05514	and direct that all corre	o prosecute this application and specification of the spondence be addressed to the
belief are believed t made are punishable	clare that all statements made here to be true; and further that these st e by fine or imprisonment, or both, pardize the validity of the applicati	atements were made with the under Section 1001 of Title	knowledge that willful 18 of the United States	false statements and the like so
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Inventor's signature	11 /11 1	1. 1.		
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